DATA SHEET

NEC

NPN SILICON GERMANIUM RF TRANSISTOR

NESG2031M16

NPN SiGe RF TRANSISTOR FOR LOW NOISE, HIGH-GAIN AMPLIFICATION 6-PIN LEAD-LESS MINIMOLD (M16, 1208 PKG)

FEATURES

- The device is an ideal choice for low noise, high-gain amplification
  NF = 0.8 dB TYP., G_a = 17.0 dB TYP. @ V_{CE} = 2 V, I_C = 5 mA, f = 2 GHz
  NF = 1.3 dB TYP., G_a = 10.0 dB TYP. @ V_{CE} = 2 V, I_C = 5 mA, f = 5.2 GHz
- Maximum stable power gain: MSG = 21.5 dB TYP. @ V_{CE} = 3 V, I_C = 20 mA, f = 2 GHz
- High breakdown voltage technology for SiGe Tr. adopted: V_{CEO} (absolute maximum ratings) = 5.0 V
- 6-pin lead-less minimold (M16, 1208 PKG)

<R> ORDERING INFORMATION

Part Number	Order Number	Package	Quantity	Supplying Form
NESG2031M16	NESG2031M16-A	6-pin lead-less minimold (M16, 1208 PKG) (Pb-Free)	50 pcs (Non reel)	• 8 mm wide embossed taping • Pin 1 (Collector), Pin 6 (Emitter) face the perforation side of the tape
NESG2031M16-T3	NESG2031M16-T3-A		10 kpcs/reel	

Remark To order evaluation samples, please contact your nearby sales office.
Unit sample quantity is 50 pcs.

ABSOLUTE MAXIMUM RATINGS (T_A = +25°C)

Parameter	Symbol	Ratings	Unit
Collector to Base Voltage	V_{CBO}	13.0	V
Collector to Emitter Voltage	V_{CEO}	5.0	V
Emitter to Base Voltage	V_{EBO}	1.5	V
Collector Current	I_C	35	mA
Total Power Dissipation	P_{tot} Note	175	mW
Junction Temperature	T_j	150	°C
Storage Temperature	T_{stg}	−65 to +150	°C

Note Mounted on 1.08 cm^2 × 1.0 mm (t) glass epoxy PCB

Caution Observe precautions when handling because these devices are sensitive to electrostatic discharge.

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The mark <R> shows major revised points.

The revised points can be easily searched by copying an "<R>" in the PDF file and specifying it in the "Find what:" field.

ELECTRICAL CHARACTERISTICS (T_A = +25°C)

Parameter	Symbol	Test Conditions	MIN.	TYP.	MAX.	Unit
DC Characteristics						
Collector Cut-off Current	I_{CBO}	V_{CB} = 5 V, I_E = 0 mA	–	–	100	nA
Emitter Cut-off Current	I_{EBO}	V_{EB} = 1 V, I_C = 0 mA	–	–	100	nA
DC Current Gain	h_{FE} Note 1	V_{CE} = 2 V, I_C = 5 mA	130	190	260	–
RF Characteristics						
Gain Bandwidth Product	f_T	V_{CE} = 3 V, I_C = 20 mA, f = 2 GHz	20	25	–	GHz
Insertion Power Gain	$\|S_{21e}\|^2$	V_{CE} = 3 V, I_C = 20 mA, f = 2 GHz	16.0	18.0	–	dB
Noise Figure (1)	NF	V_{CE} = 2 V, I_C = 5 mA, f = 2 GHz, $Z_S = Z_{Sopt}$, $Z_L = Z_{Lopt}$	–	0.8	1.1	dB
Noise Figure (2)	NF	V_{CE} = 2 V, I_C = 5 mA, f = 5.2 GHz, $Z_S = Z_{Sopt}$, $Z_L = Z_{Lopt}$	–	1.3	–	dB
Associated Gain (1)	G_a	V_{CE} = 2 V, I_C = 5 mA, f = 2 GHz, $Z_S = Z_{Sopt}$, $Z_L = Z_{Lopt}$	15.0	17.0	–	dB
Associated Gain (2)	G_a	V_{CE} = 2 V, I_C = 5 mA, f = 5.2 GHz, $Z_S = Z_{Sopt}$, $Z_L = Z_{Lopt}$	–	10.0	–	dB
Reverse Transfer Capacitance	C_{re} Note 2	V_{CB} = 2 V, I_E = 0 mA, f = 1 MHz	–	0.15	0.25	pF
Maximum Stable Power Gain	MSG Note 3	V_{CE} = 3 V, I_C = 20 mA, f = 2 GHz	19.0	21.5	–	dB
Gain 1 dB Compression Output Power	$P_{O\ (1\ dB)}$	V_{CE} = 3 V, $I_{C\ (set)}$ = 20 mA (RF OFF), f = 2 GHz, $Z_S = Z_{Sopt}$, $Z_L = Z_{Lopt}$	–	13	–	dBm
Output 3rd Order Intercept Point	OIP_3	V_{CE} = 3 V, $I_{C\ (set)}$ = 20 mA (RF OFF), f = 2 GHz, $Z_S = Z_{Sopt}$, $Z_L = Z_{Lopt}$	–	23	–	dBm

Notes 1. Pulse measurement: PW ≤ 350 μs, Duty Cycle ≤ 2%

2. Collector to base capacitance when the emitter grounded

3. $MSG = \left| \frac{S_{21}}{S_{12}} \right|$

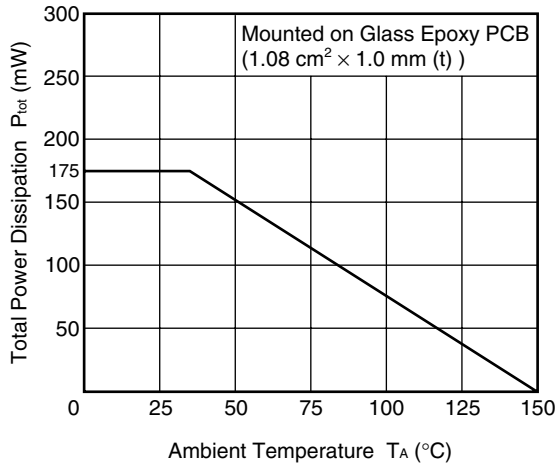
h_{FE} CLASSIFICATION

<R>

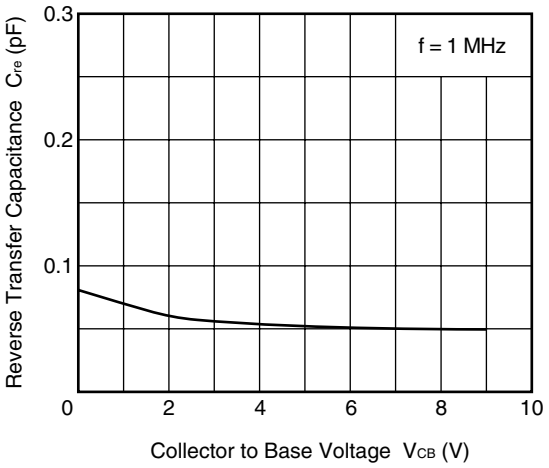
Rank	FB/YFB
Marking	zF
h_{FE} Value	130 to 260

<R> **TYPICAL CHARACTERISTICS (T_A = +25°C, unless otherwise specified)**

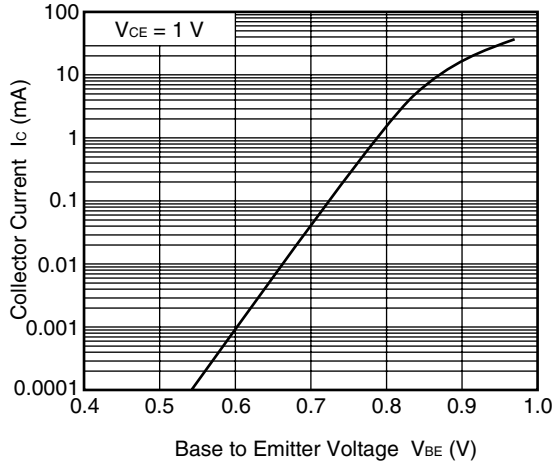
TOTAL POWER DISSIPATION vs. AMBIENT TEMPERATURE



REVERSE TRANSFER CAPACITANCE vs. COLLECTOR TO BASE VOLTAGE



COLLECTOR CURRENT vs. BASE TO EMITTER VOLTAGE



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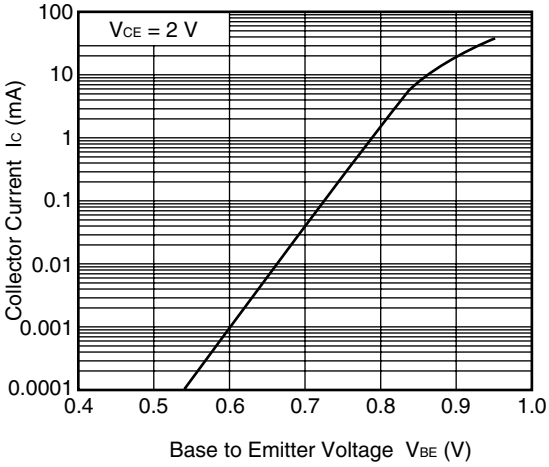
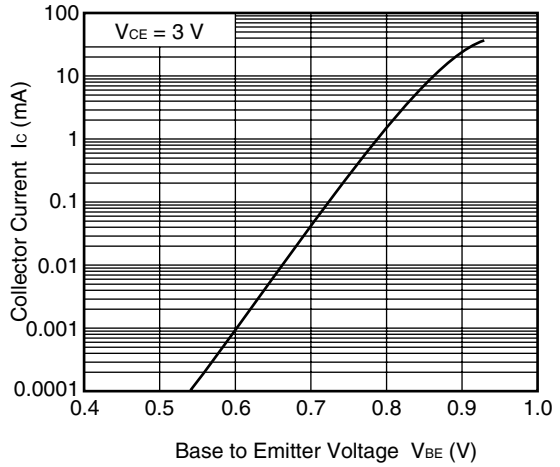
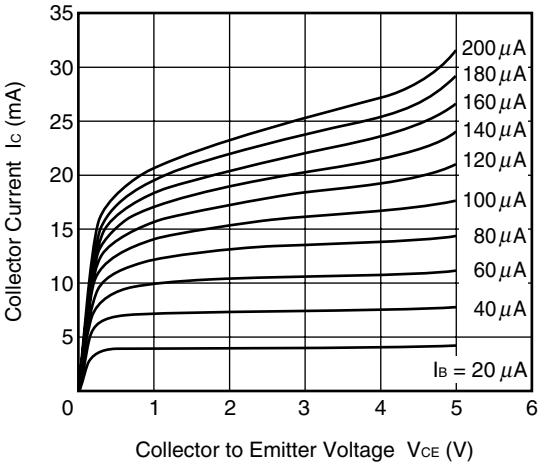


COLLECTOR CURRENT vs. BASE TO EMITTER VOLTAGE

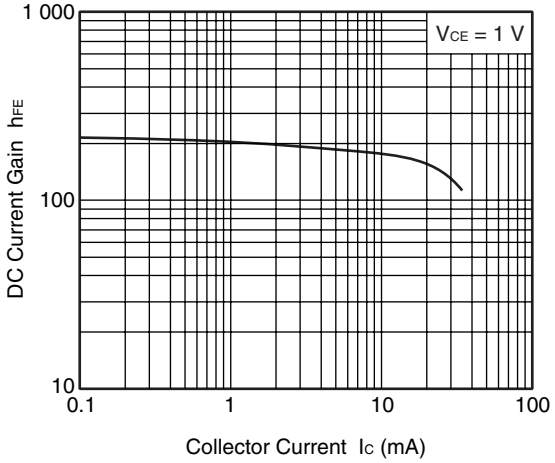


COLLECTOR CURRENT vs. COLLECTOR TO EMITTER VOLTAGE



Remark The graphs indicate nominal characteristics.

DC CURRENT GAIN vs.
COLLECTOR CURRENT



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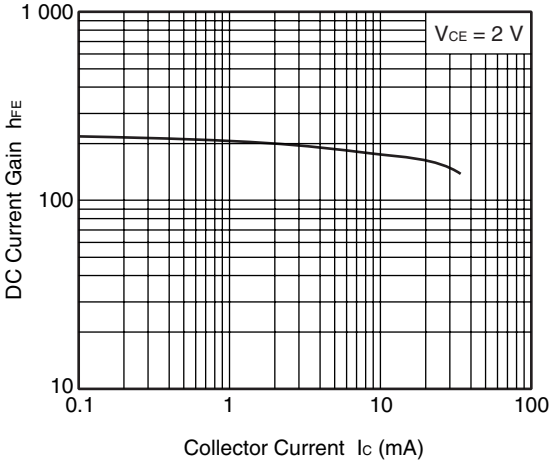
COLLECTOR CURRENT



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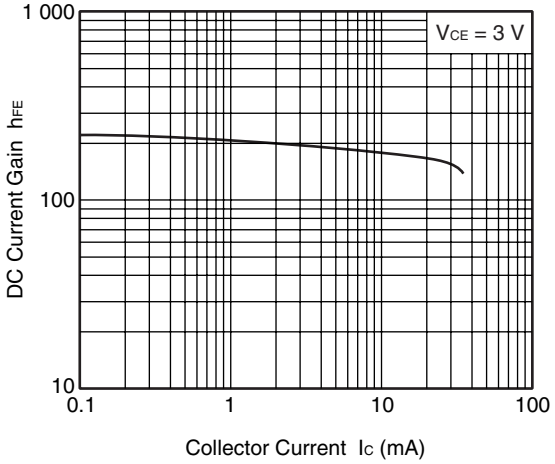
COLLECTOR CURRENT



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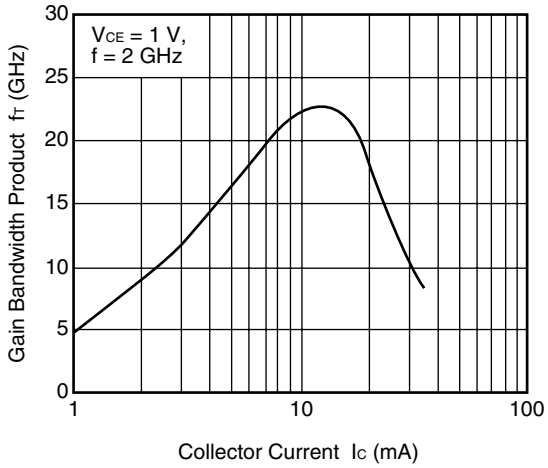
GAIN BANDWIDTH PRODUCT vs. COLLECTOR CURRENT



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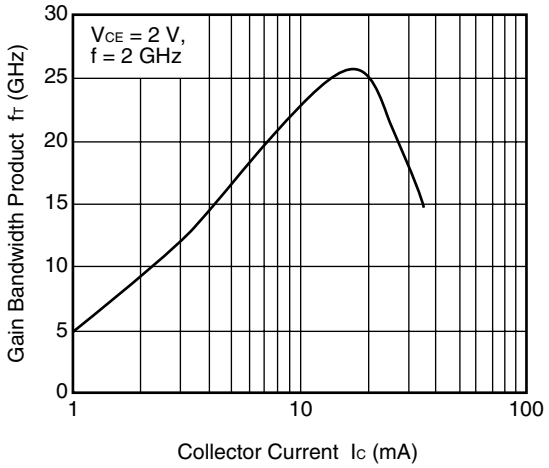

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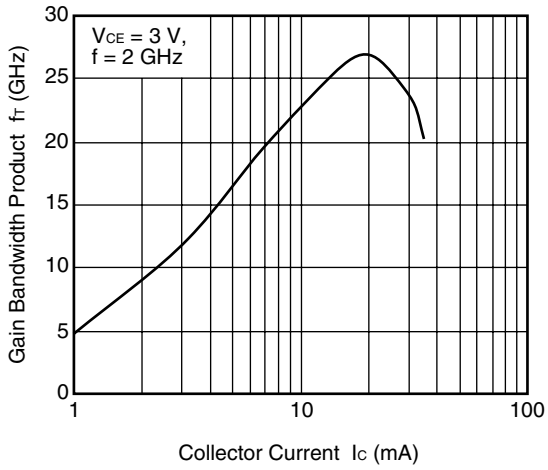
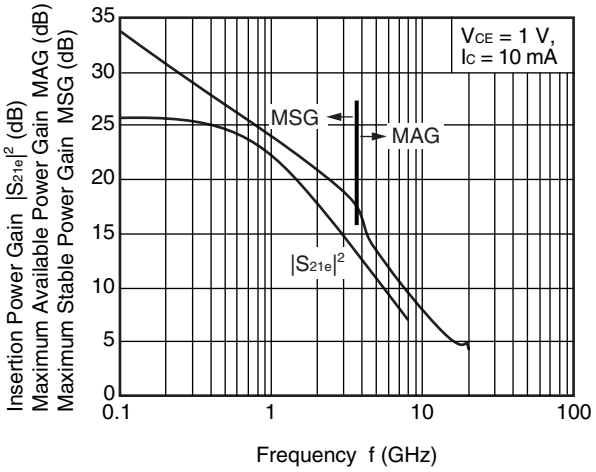


INSERTION POWER GAIN, MAG, MSG vs. FREQUENCY



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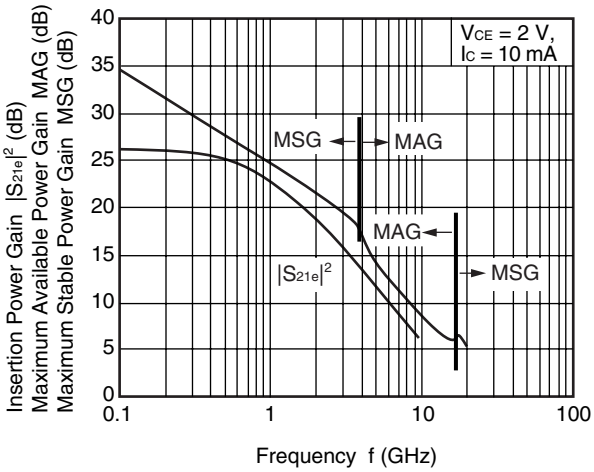

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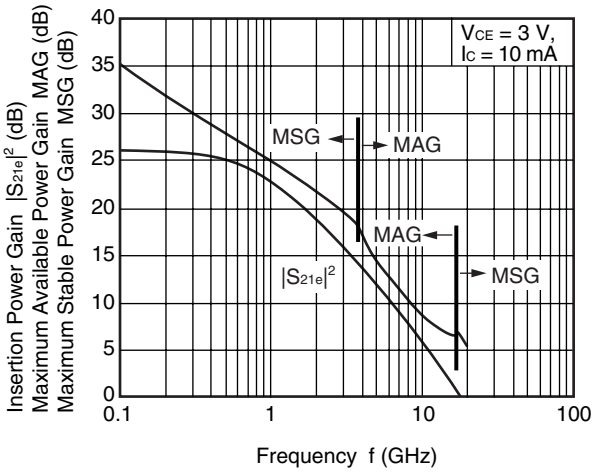

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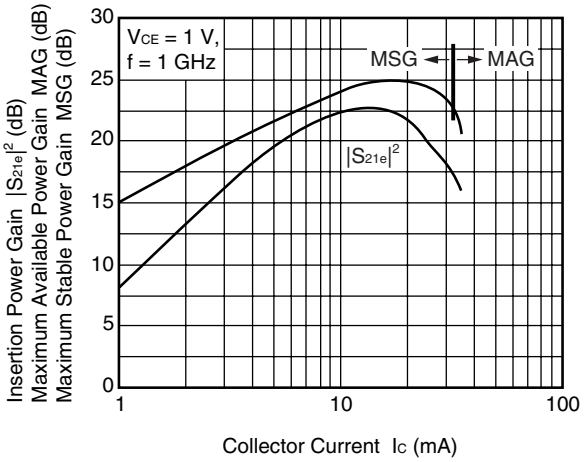

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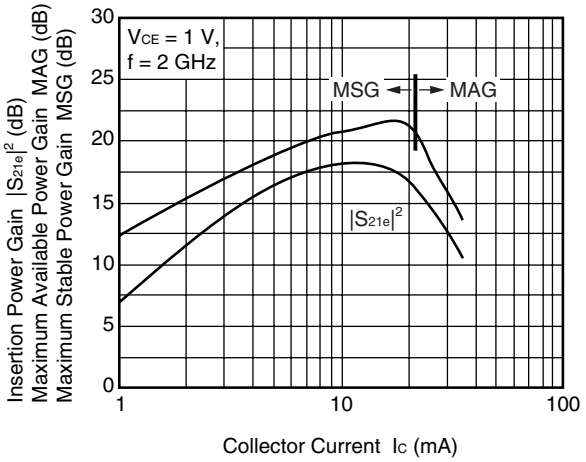

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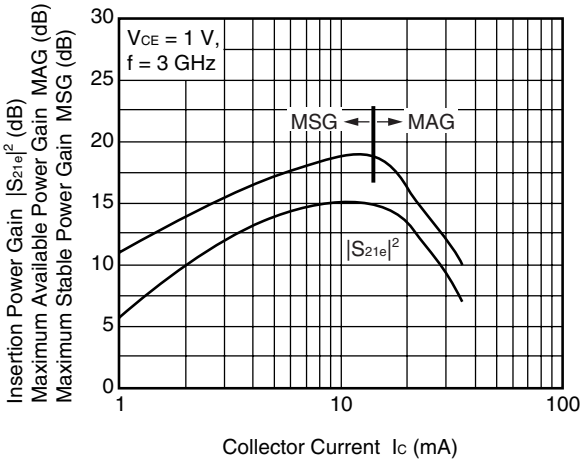

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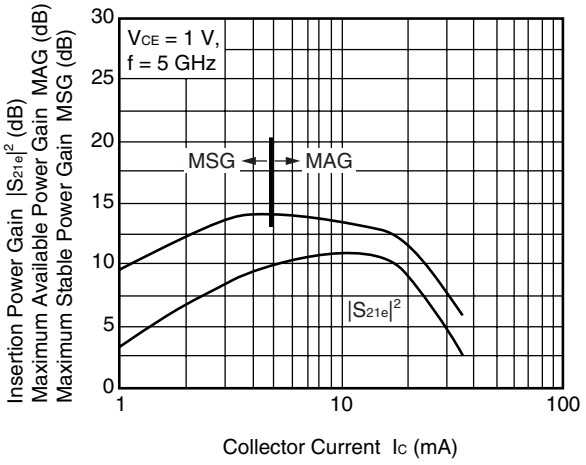

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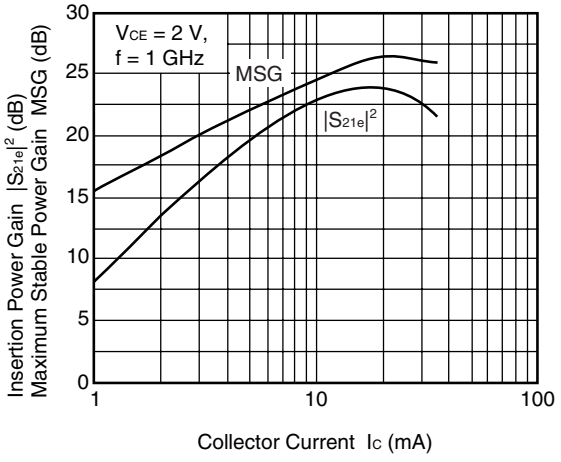

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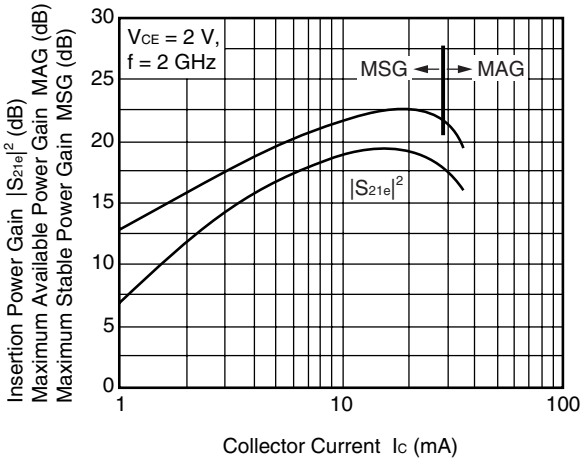

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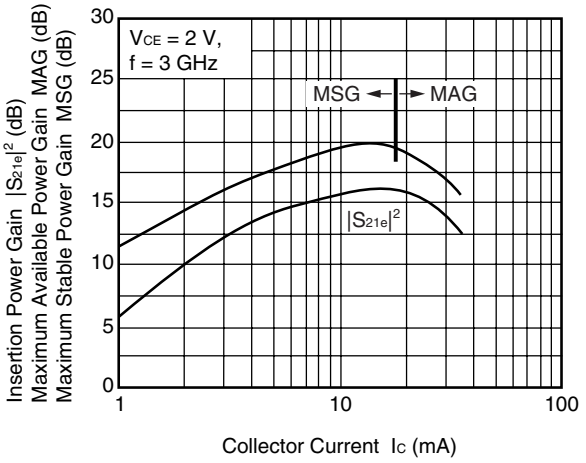

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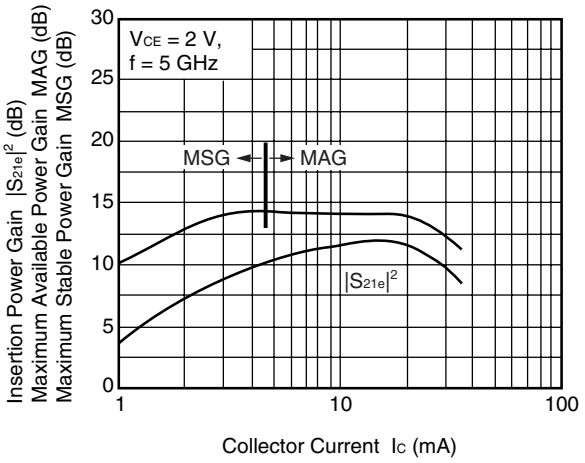

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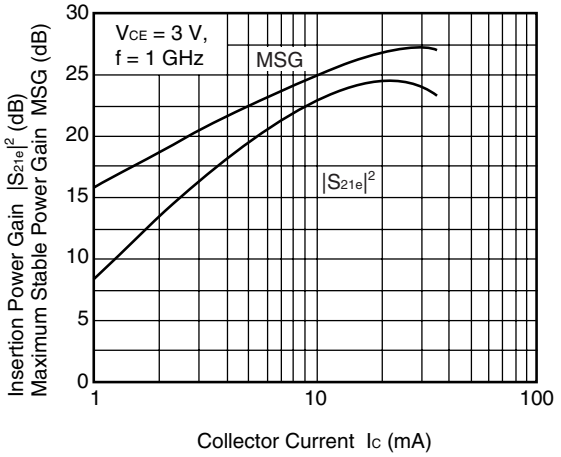

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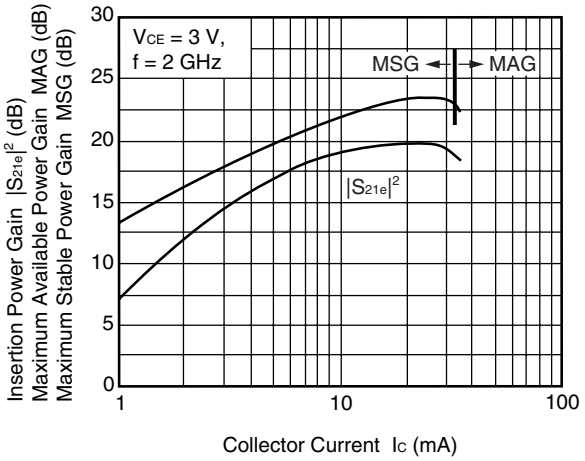

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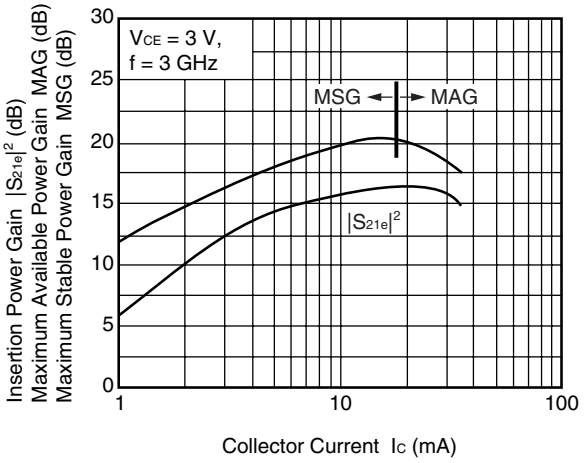

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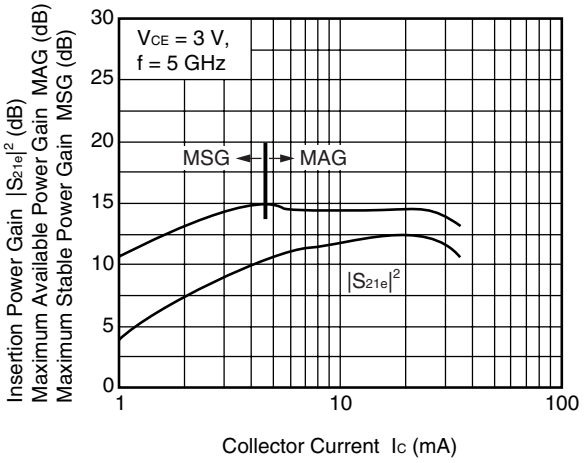
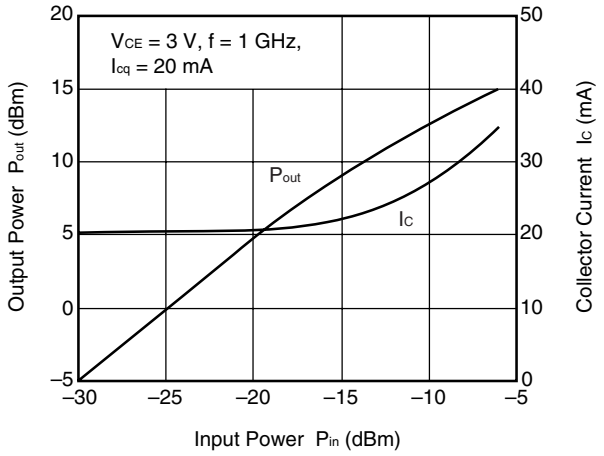


Remark The graphs indicate nominal characteristics.

OUTPUT POWER, COLLECTOR CURRENT vs. INPUT POWER



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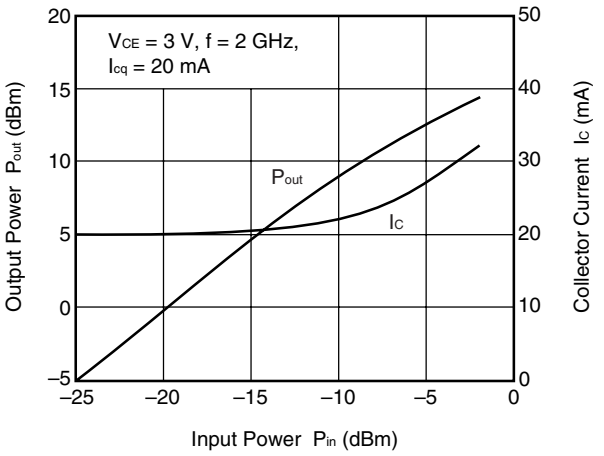

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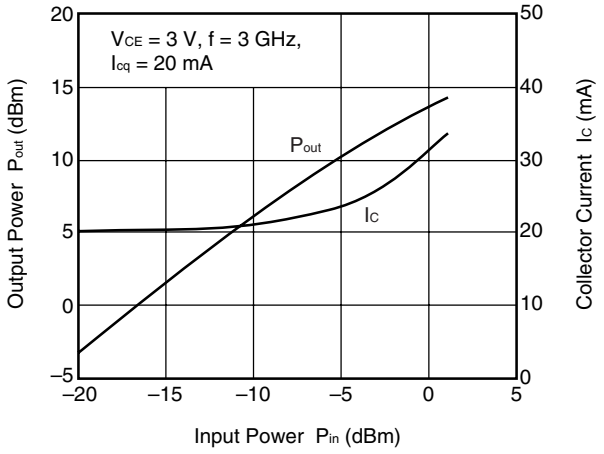

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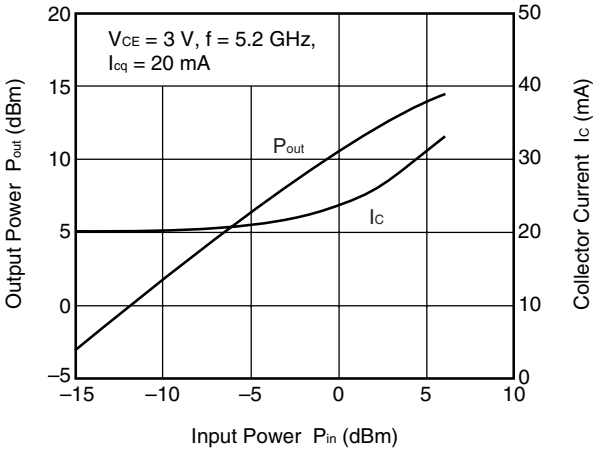

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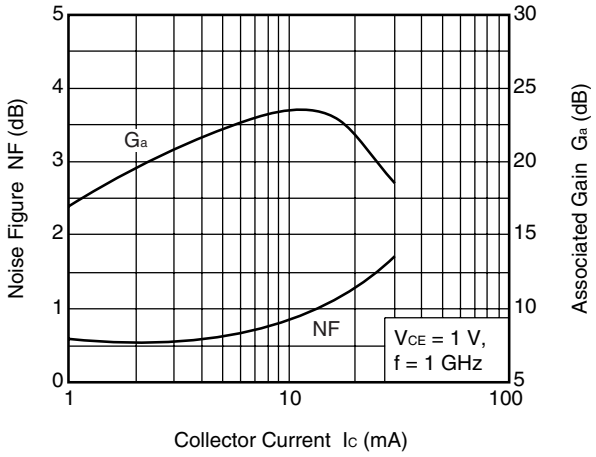
NOISE FIGURE, ASSOCIATED GAIN vs. COLLECTOR CURRENT



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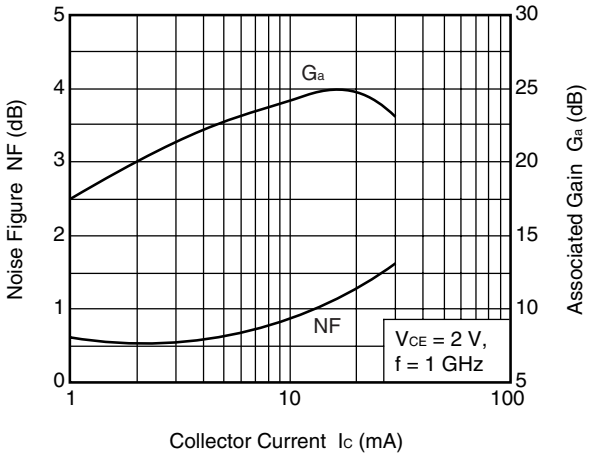

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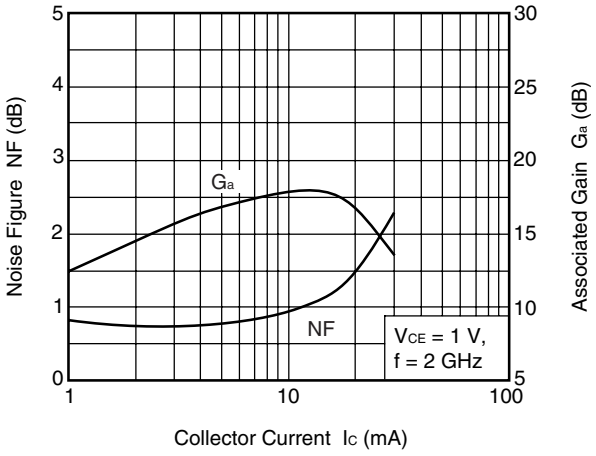

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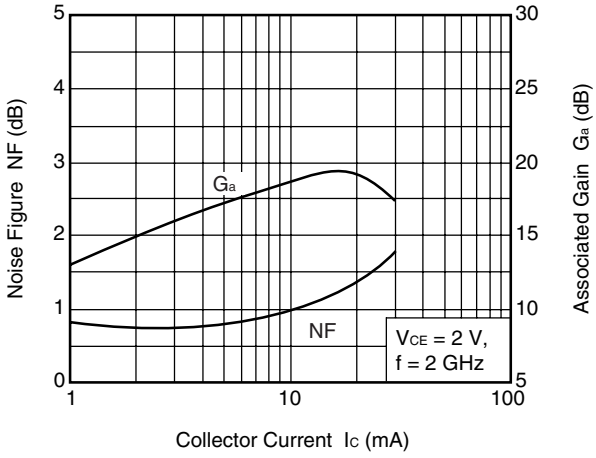

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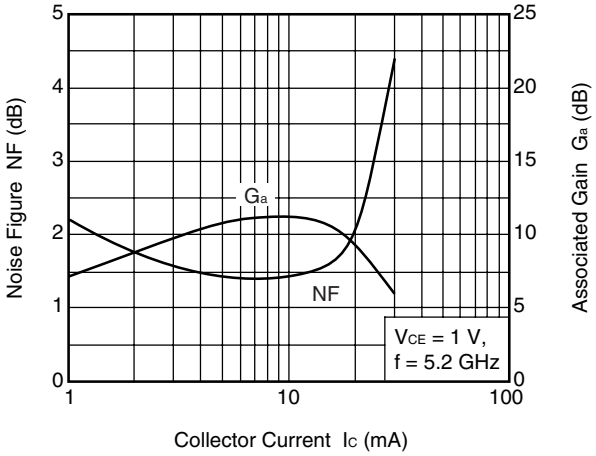

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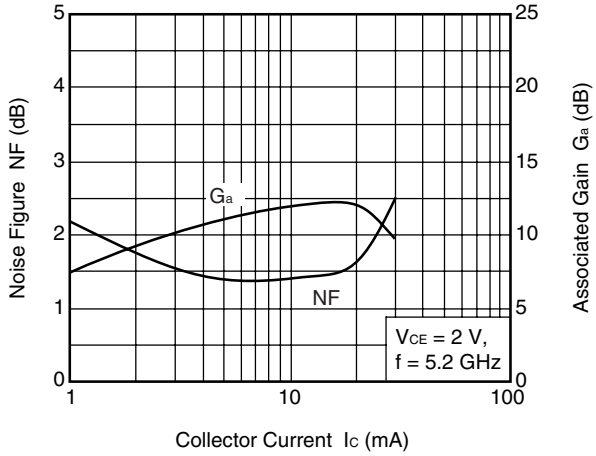

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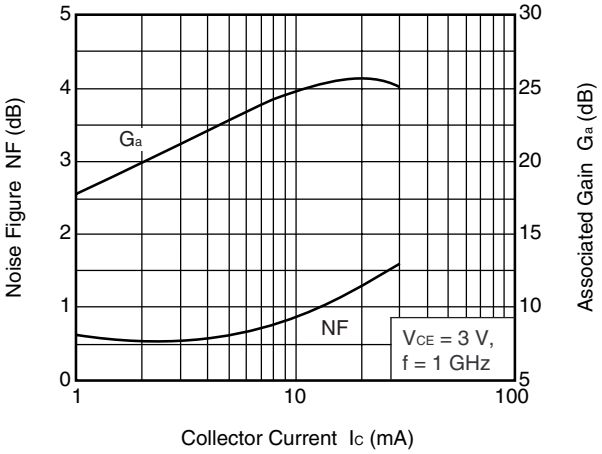
NOISE FIGURE, ASSOCIATED GAIN vs. COLLECTOR CURRENT



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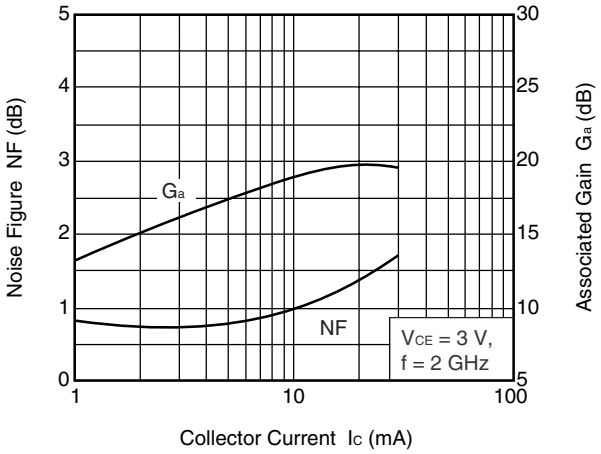
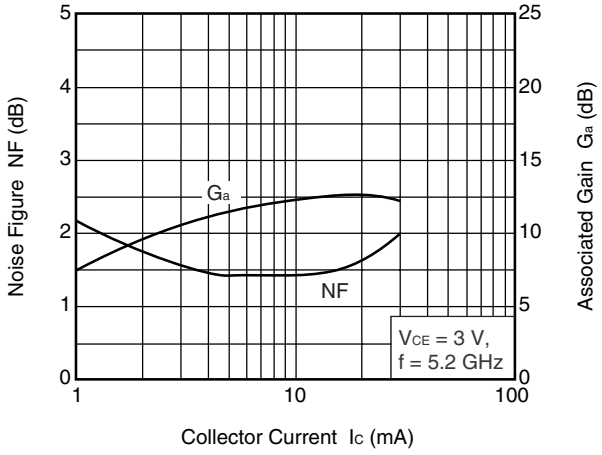


NOISE FIGURE, ASSOCIATED GAIN vs. COLLECTOR CURRENT



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<R> **S-PARAMETERS**

S-parameters and noise parameters are provided on our Web site in a format (S2P) that enables the direct import of the parameters to microwave circuit simulators without the need for keyboard inputs.

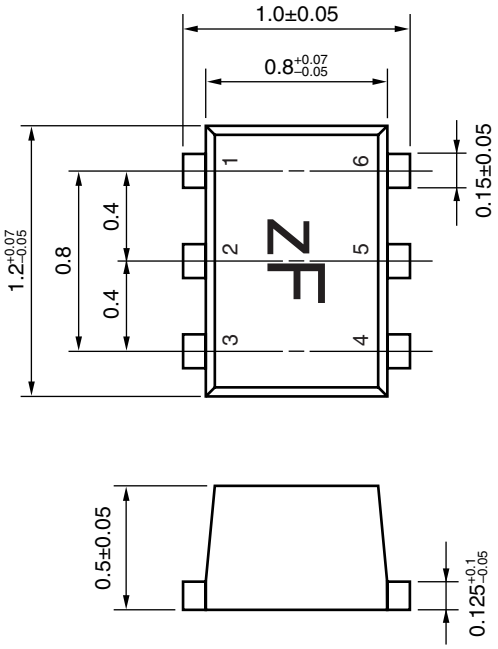
Click here to download S-parameters.

[RF and Microwave] → [Device Parameters]

URL http://www.necel.com/microwave/en/

PACKAGE DIMENSIONS

6-PIN LEAD-LESS MINIMOLD (M16, 1208 PKG) (UNIT: mm)



PIN CONNECTIONS

1. Collector
2. Emitter
3. Emitter
4. Base
5. Emitter
6. Emitter

Caution All four Emitter-pins should be connected to PWB in order to obtain better Electrical performance and heat sinking.

- **The information in this document is current as of September, 2009. The information is subject to change without notice. For actual design-in, refer to the latest publications of NEC Electronics data sheets, etc., for the most up-to-date specifications of NEC Electronics products. Not all products and/or types are available in every country. Please check with an NEC Electronics sales representative for availability and additional information.**
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